Collector

Emitter

2SA2072

(SC-63)

<SOT-428>

CPT3

Base



PNP -3.0A -60V Middle Power Transistor

Parameter	Value
V_{CEO}	-60V
I _C	-3.0A

Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SC5824 / 2SC5825
- 3) Low V_{CE(sat)}

•Inner circuit

 $V_{CE(sat)} = -500 \text{mV Max.}$ ($I_C/I_B = -2A/-0.2A$)

4) Lead Free/RoHS Compliant.

Applications

Outline

Base Collector

Emitter

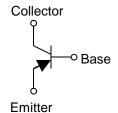
2SA2071

(SC-62)

<SOT-89>

MPT3

Motor driver, LED driver Power supply



Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SA2071	MPT3	4540	T100	180	12	1,000	UN
2SA2072	CPT3	6595	TL	330	16	2,500	A2072

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	-60	V
Collector-emitter voltage		V _{CEO}	-60	V
Emitter-base voltage		V _{EBO}	-6	V
Collector ourrent	DC	I _C	-3.0	А
Collector current	Pulsed	I _{CP} *1	-6.0	А
	2SA2071		0.5 *2	W
Dawar dissination	25A2U/ I		2 ^{*3}	W
Power dissipation	0040070	$ P_D$	1 *4	W
	2SA2072		10 ^{*5}	W
Junction temperature		T _j	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

^{*1} Pw=100ms, single pulse *2 Each terminal mounted on a reference land

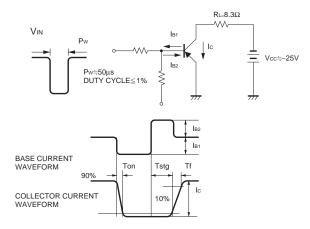
^{*3} Mounted on a ceramic board (40×40×0.7mm) *4 Mounted on a substrate *5 T_C=25°C

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	$I_C = -1mA$	-60	-	-	V
Collector-base breakdown voltage	BV _{CBO}	$I_C = -100 \mu A$	-60	-	-	V
Emitter-base breakdown voltage	BV_{EBO}	$I_E = -100 \mu A$	-6	-	ı	V
Collector cut-off current	I _{CBO}	$V_{CB} = -40V$	-	-	-1.0	μА
Emitter cut-off current	I _{EBO}	$V_{EB} = -4V$	ı	ı	-1.0	μА
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -2A, I_B = -0.2A$	-	-0.20	-0.50	V
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	120	-	270	-
Transition frequency	f _T	$V_{CE} = -10V, I_{E} = 10mA$ f=10MH _z	-	180	-	MHz
Output capacitance	C_ob	$V_{CB} = -10V$, $I_E = 0A$ f = 1MHz	ı	50	ı	pF
Turn-on time	t _{on} *1	I _C = -3A	ı	20	ı	ns
Storage time	t _{stg} *1	$I_{B1} = -300 \text{mA}$ $I_{B2} = 300 \text{mA}$	-	150	ı	ns
Fall time	t _f *1	V _{CC} [≃] –25V	-	20	ı	ns

^{*1} See switching time test circuit

•Switching time test circuit



●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

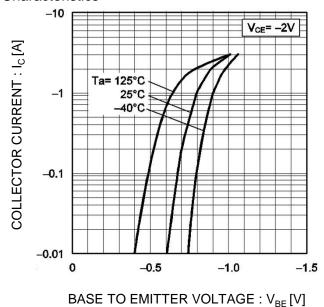
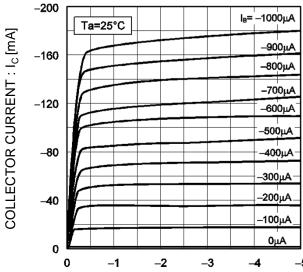


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : V_{CE}[V]

Fig.3 DC Current Gain vs. Collector Current(I)

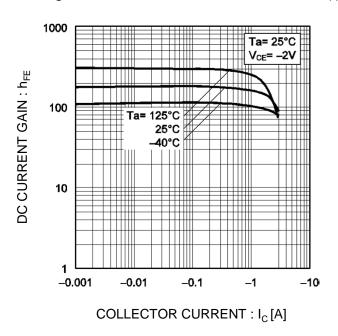
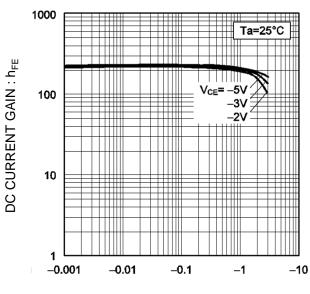
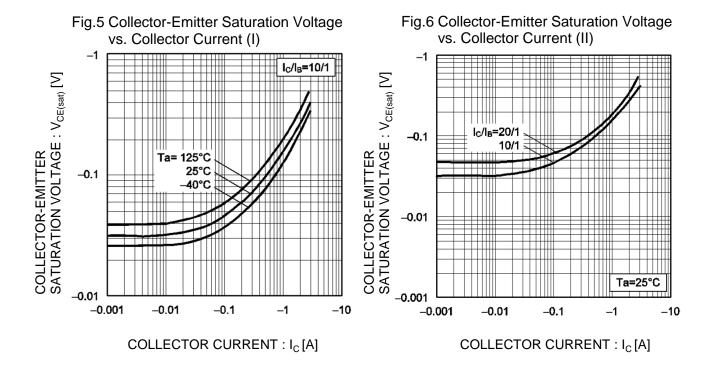


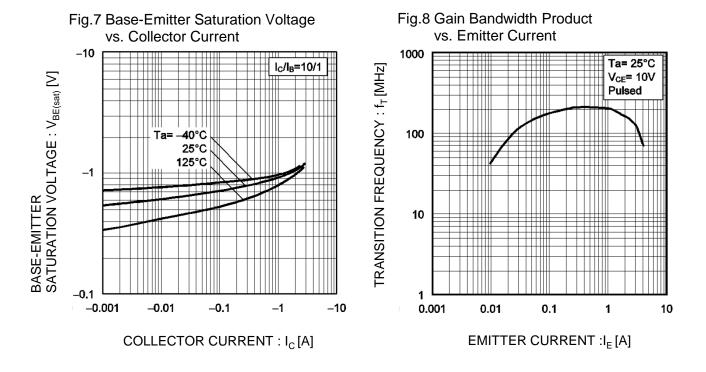
Fig.4 DC current gain vs. output current (II)



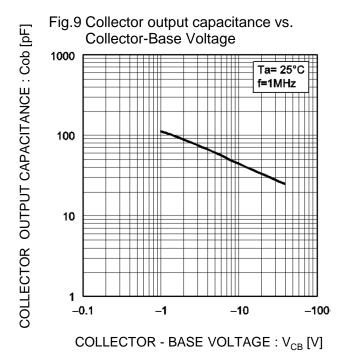
COLLECTOR CURRENT : I_C[A]

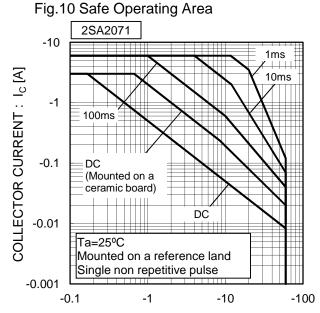
●Electrical characteristic curves(Ta = 25°C)



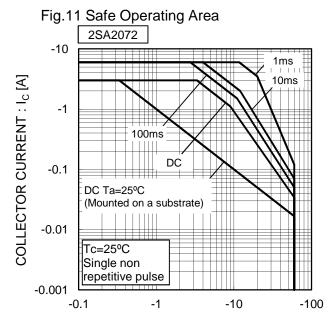


●Electrical characteristic curves(Ta = 25°C)



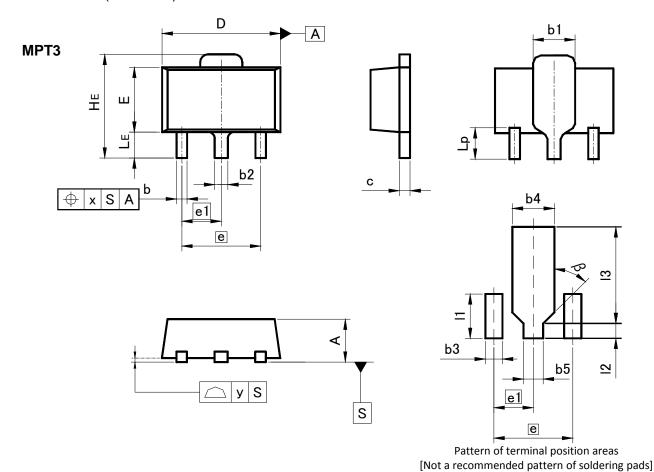


COLLECTOR TO EMITTER VOLTAGE: V_{CE} [V]



COLLECTOR TO EMITTER VOLTAGE : $V_{CE}[V]$

●Dimensions (Unit : mm)

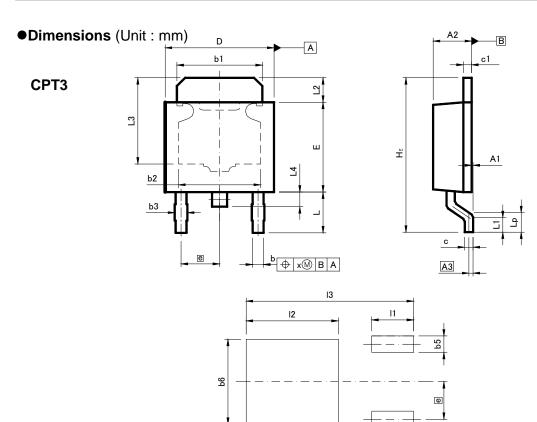


DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
Е	2.40	2.70	0.094	0.106	
е	3.0	00	0.118		
e1	1.50		0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х	_	0.15	_	0.006	
У	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
b3		0.65	1	0.026
b4		1.70	1	0.067
b5	_	0.75	-	0.030
l1	_	1.71	-	0.067
12	_	0.58	-	0.023
13	_	3.72	-	0.146
β	45°		45	0

Dimension in mm / inches

6/7



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
A1	0.00	0.15	0.000	0.006	
A2	2.20	2.50	0.087	0.098	
A3	0.	25	0.010		
b	0.55	0.75	0.022	0.030	
b1	5.00	5.30	0.197	0.209	
b2	5.	00	0.1	97	
b3	0.	75	0.030		
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.30	6.70	0.248	0.264	
E	5.40	5.80	0.213	0.228	
е	2.	30	0.091		
HE	9.00	10.00	0.354	0.394	
L	2.20	2.80	0.087	0.110	
L1	0.80	1.40	0.031	0.055	
L2	1.20	1.80	0.047	0.071	
L3	5.30		0.209		
L4	0.90		0.0)35	
Lp	1.00	1.60	0.039	0.063	
Х	_	0.25	_	0.010	

DIM	MILIM	ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
b5	ı	1.00	-	0.04
b6	ı	5.20	-	0.205
- 11	ı	2.50	-	0.098
12	ı	5.50	-	0.217
13	_	10.00	_	0.394

Dimension in mm / inches

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